**Key Parameters**

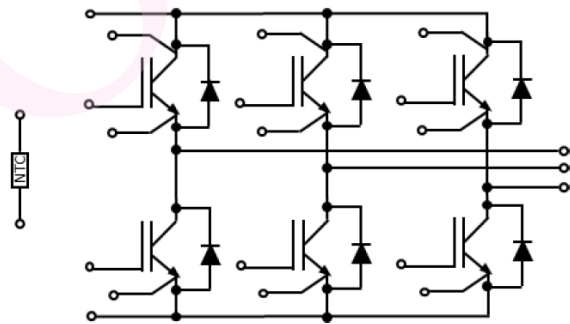
V_{CES}	= 650V
I_c	= 400A

Features

- Low $V_{ce(sat)}$
- Fast switching
- High ruggedness
- High short circuit capability

Applications

- Inverter for motor drive
- Water pumps
- Wind turbines



Equivalent Circuit Schematic

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Absolute Maximum Ratings: IGBT, Inverter						
Symbol	Characteristic	Value	Unit			
V_{CES}	Collector-Emitter Voltage	650	V			
I_{CDC}	Continuous DC Collector Current	400	A			
I_{CRM}	Peak Collector Current	800	A			
V_{GES}	Gate-Emitter Voltage	± 20	V			
$P_{D(max)}$	Total Power Dissipation ($T_c=25^\circ C, T_j=175^\circ C$)	1650	W			
IGBT Characteristics						
Symbol	Characteristic	Conditions	Value			Unit
			Min.	Typ.	Max.	
BV_{CES}	Collector-Emitter breakdown Voltage	$V_{GE}=0V, I_C=250\mu A, T_{vj}=25^\circ C$	650			V
I_{CES}	Collector-Emitter leakage Current	$V_{CE}=650V, V_{GE}=0V, T_{vj}=25^\circ C$			5.0	mA
I_{GES}	Gate-Emitter leakage Current	$V_{CE}=0V, V_{GE}=\pm 20V, T_{vj}=25^\circ C$			± 500	ηA
$V_{GE(th)}$	Gate-emitter Threshold Voltage	$V_{GE}=V_{CE}, I_C=4mA, T_{vj}=25^\circ C$	5.0	5.9	6.8	V
$V_{CE(sat)}$	Collector-Emitter Saturation Voltage	$I_C=400A, V_{GE}=15V, T_{vj}=25^\circ C$		1.5	1.8	V
		$I_C=400A, V_{GE}=15V, T_{vj}=150^\circ C$		1.75		V
Q_G	Gate Charge	$V_{CC}=300V, V_{GE}=0/15V, I_C=400A, T_{vj}=25^\circ C$		2.45		μC
C_{iss}	Input Capacitance	$V_{CE}=25V, V_{GE}=0V, f=1MHz, T_{vj}=25^\circ C$		33		ηF
C_{oss}	Output Capacitance	$f=1MHz, T_{vj}=25^\circ C$		1.5		ηF
$t_{d(on)}$	Turn-on Delay Time	$I_C=400A$		89		ηs
t_r	Rise Time	$V_{CE}=300V$		99		ηs
$t_{d(off)}$	Turn-off Delay Time	$V_{GE}=\pm 15V$		220		ηs
t_f	Fall Time	$R_G=1.8\Omega$		79		ηs
E_{on}	Energy Dissipation During Turn-on Time	$T_{vj}=25^\circ C, L_{load}=0.82mH$		5.5		mJ
E_{off}	Energy Dissipation During Turn-off Time	Energy loss include tail and diode reverse recovery		9.8		mJ
$t_{d(on)}$	Turn-on Delay Time	$I_C=400A$		108		ηs
t_r	Rise Time	$V_{CE}=300V$		100		ηs
$t_{d(off)}$	Turn-off Delay Time	$V_{GE}=\pm 15V$		250		ηs
t_f	Fall Time	$R_G=1.8\Omega$		130		ηs
E_{on}	Energy Dissipation During Turn-on Time	$T_{vj}=150^\circ C, L_{load}=0.82mH$		8.5		mJ
E_{off}	Energy Dissipation During Turn-off Time	Energy loss include tail and diode reverse recovery		12.8		mJ
T_{sc}	Short circuit withstand time	$V_{GE}=15V, T_{vj}=150^\circ C, V_{CC}\leq 360V,$	10			μs

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Absolute Maximum Ratings: Diode, Inverter						
Symbol	Characteristic	Value	Unit			
V_{RRM}	Repetitive peak reverse voltage	650	V			
I_F	Continuous DC forward current	400	A			
I_{FRM}	Repetitive peak forward current	800	A			
Diode Characteristics						
Symbol	Characteristic	Conditions	Value			Unit
			Min.	Typ.	Max.	
V_F	Forward Voltage	$I_F=400A, T_{vj}=25^{\circ}C$		1.6	1.9	V
		$I_F=400A, T_{vj}=150^{\circ}C$		1.4		V
Q_{rr}	Recovered Charge	$I_F=400 A$		16.6		μC
I_{rrm}	Peak Reverse Recovery Current	$V_R=300V$		117		A
E_{rr}	Reverse Recovery Energy	$-di_F/dt = 2260A/\mu s$ $T_{vj}=25^{\circ}C$		3.1		mJ
Module Characteristics						
Symbol	Characteristic	Conditions	Value			Unit
			Min.	Typ.	Max.	
V_{isol}	Isolation voltage	$t=1min, f=50Hz$	2500			V
T_{jmax}	Maximum Junction Temperature				175	$^{\circ}C$
T_{vjop}	Operating Junction Temperature		-40		150	$^{\circ}C$
T_{stg}	Storage Temperature		-40		125	$^{\circ}C$
$R_{CC'+EE'}$	Module lead resistance terminal to chip			1.0		m Ω
L_{SCE}	Stray Inductance, Module			30		nH
$R_{\theta jc}$	Junction-to Case	per IGBT-inverter		0.09		$^{\circ}C/W$
		per Diode-inverter		0.17		$^{\circ}C/W$
$R_{\theta cs}$	Case to Sink	per IGBT-inverter		0.08		$^{\circ}C/W$
		per Diode-inverter		0.085		$^{\circ}C/W$
M_t	Module Electrodes Torque	Recommended(M5)	3.0		6.0	N·m
M_s	Module-to-Sink Torque	Recommended(M6)	3.0		6.0	N·m
G	Weight of Module			485		g
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• Typical Electrical Characteristics

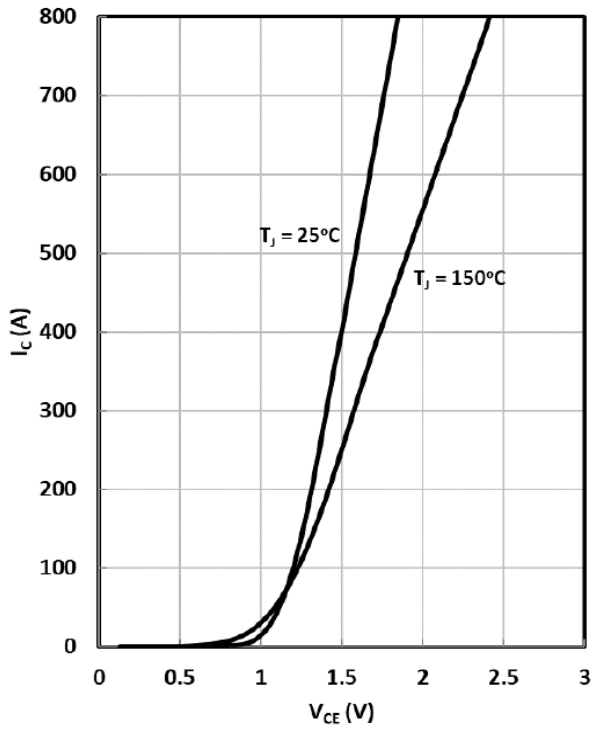


Fig. 1 IGBT (Inverter) Output Characteristics

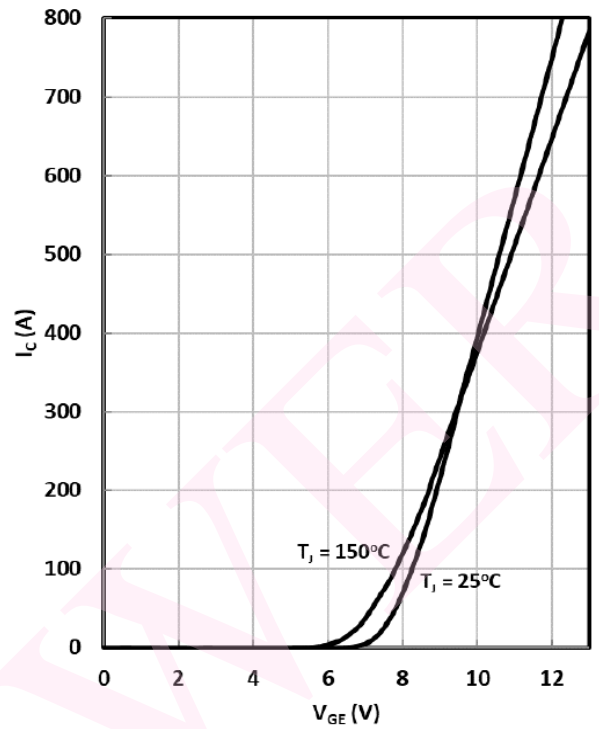


Fig. 2 IGBT (Inverter) Transfer Characteristics

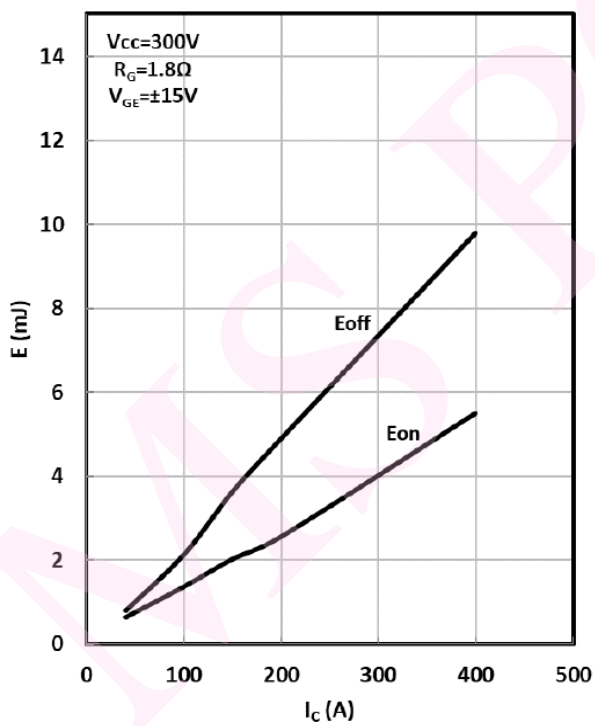


Fig. 3 IGBT (Inverter) Switching Loss vs. Ic

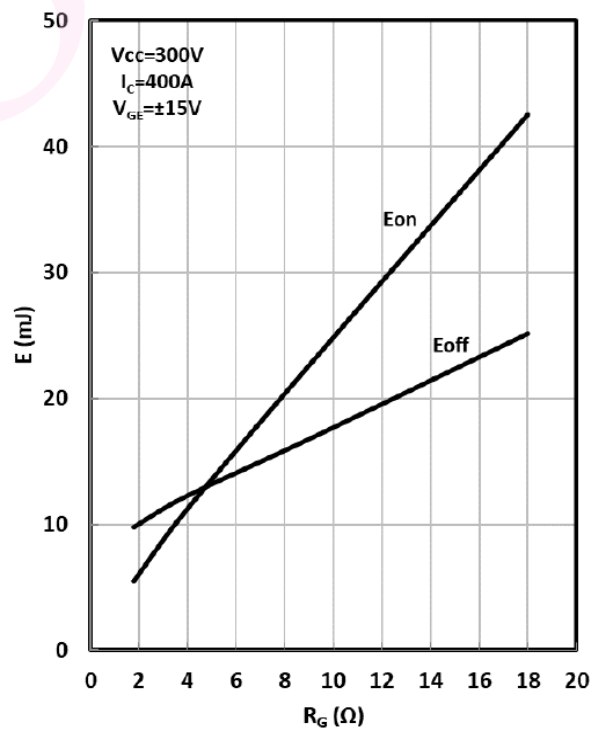


Fig. 4 IGBT (Inverter) Switching Loss vs. Rg

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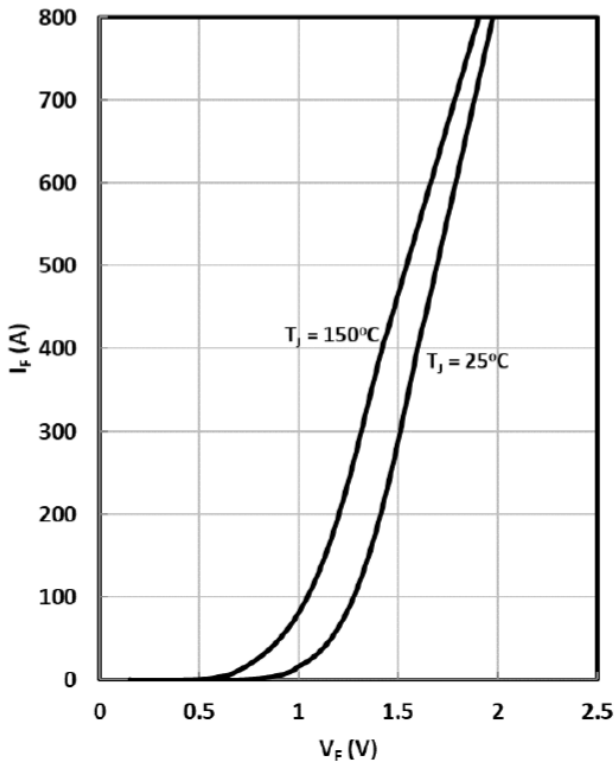
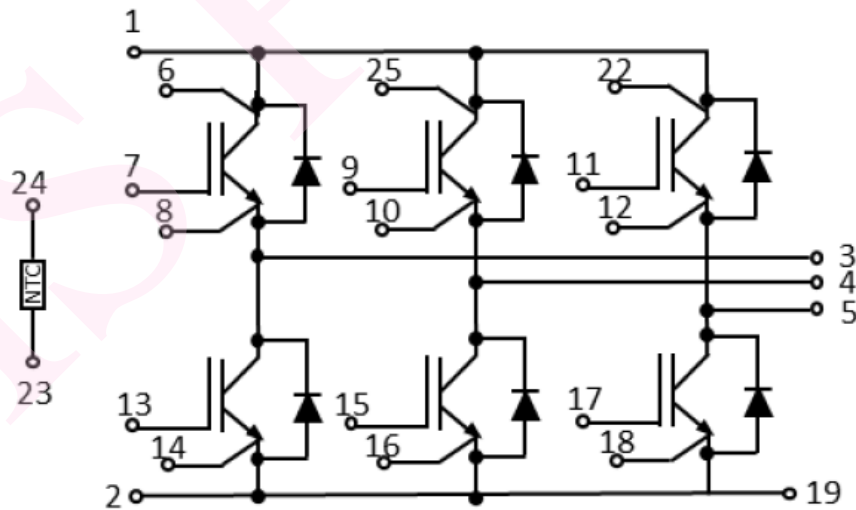


Fig. 5 Diode (Inverter) Forward Characteristics

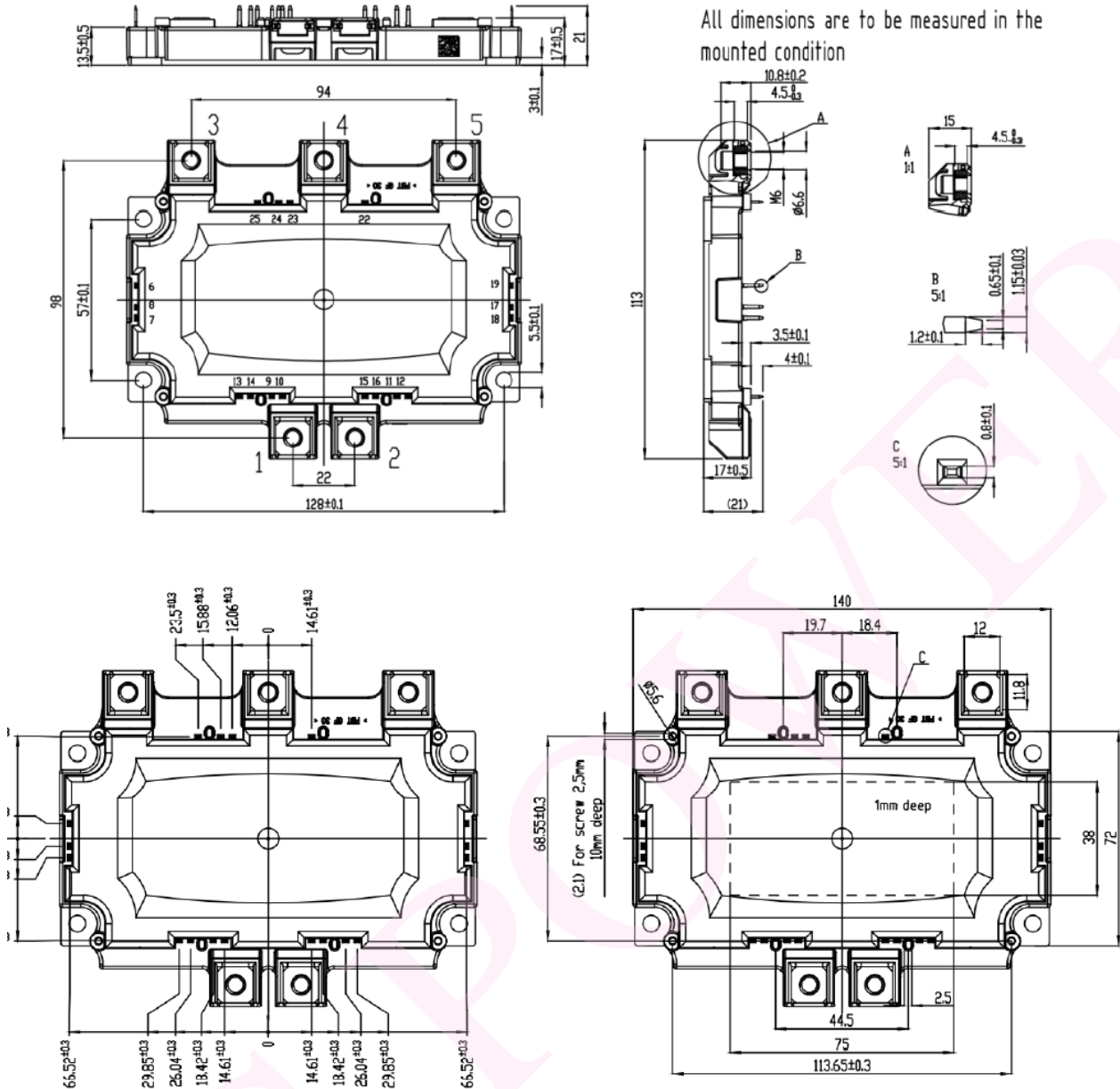


Fig. 6 RBSOA



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